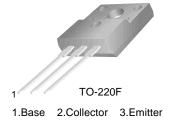


## KSB1097

### **Low Frequency Power Amplifier**

- Low Speed Switchng Industrial Use
- Complement to KSD1588



## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	- 80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	- 60	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 7	V
I <sub>C</sub>	Collector Current (DC)	- 7	Α
I <sub>CP</sub>	*Collector Current (Pulse)	- 15	А
I <sub>B</sub>	Base Current	- 3.5	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	2	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	30	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -60V, I_{E} = 0$		- 10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$		- 10	μΑ
h <sub>FE1</sub>	* DC Current Gain	$V_{CE} = -1V, I_{C} = -3A$	40	200	
h <sub>FE2</sub>		$V_{CE} = -1V, I_{C} = -5A$	20		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -5A$ , $I_B = -0.5A$		- 0.5	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	$I_C = -5A$ , $I_B = -0.5A$		- 1.5	V

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

### **h**<sub>FE</sub> Classification

Classification	R	0	Y
h <sub>FE1</sub>	40 ~ 80	60 ~ 120	100 ~ 200

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## **Typical Characteristics**

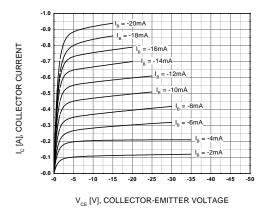


Figure 1. Static Characteristics

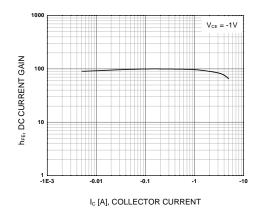


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

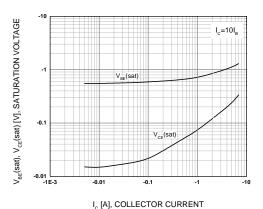


Figure 3. Saturation Voltage

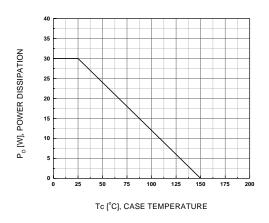


Figure 4. Power Derating

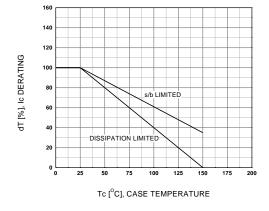


Figure 5. Power Derating

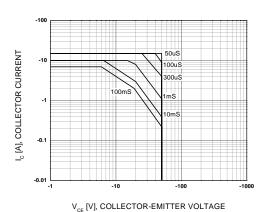
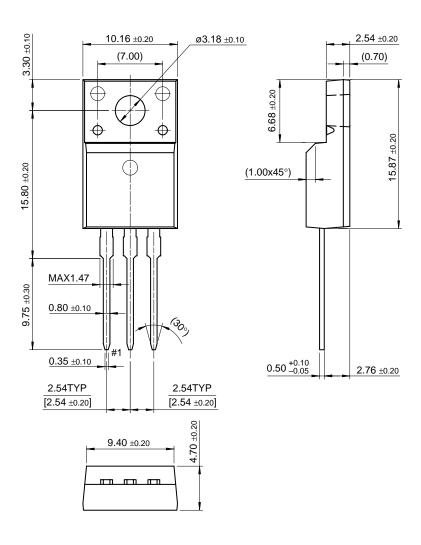


Figure 6. Safe Operating Area

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# **Package Demensions**

## TO-220F



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